## 0.8Ω, Low-Voltage, 4-Channel Analog Multiplexer

#### **General Description**

The MAX4734 is a low on-resistance, low-voltage, 4-channel CMOS analog multiplexer that operates from a single 1.6V to 3.6V supply. This device has fast switching speeds ( $t_{ON}$  = 25ns,  $t_{OFF}$  = 20ns max), handles rail-to-rail analog signals, and consumes less than 4 $\mu$ W of quiescent power. The MAX4734 has break-before-make switching.

When powered from a 3V supply, the MAX4734 features low  $0.8\Omega$  (max) on-resistance (R<sub>ON</sub>), with  $0.2\Omega$  (max) R<sub>ON</sub> matching and  $0.1\Omega$  R<sub>ON</sub> flatness. The digital logic input is 1.8V CMOS compatible when using a single 3V supply.

The MAX4734 is available in space-saving 12-pin TQFN (3mm x 3mm) and 10-pin µMAX packages.

#### **Applications**

- Power Routing
- Battery-Powered Systems
- · Audio and Video Signal Routing
- Low-Voltage Data-Acquisition Systems
- Communications Circuits
- PCMCIA Cards
- Cellular Phones
- Modems
- Hard Drives

#### **Features**

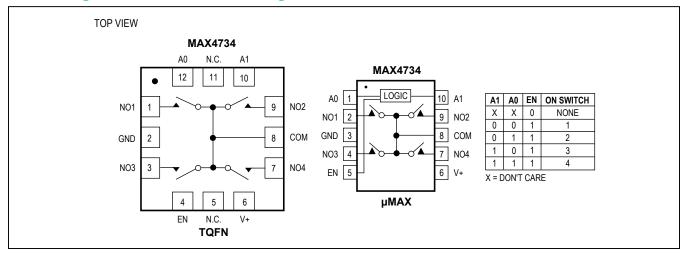
- Low Ron
  - 0.8Ω (max) (3V Supply)
  - 2Ω (max) (1.8V Supply)
- 0.1Ω (max) R<sub>ON</sub> Flatness (3V Supply)
- 1.6V to 3.6V Single-Supply Operation
- Available in Thin QFN (3mm x 3mm) Package
- High-Current Handling Capacity (150mA Continuous)
- 1.8V CMOS-Logic Compatible (3V Supply)
- Fast Switching: t<sub>ON</sub> = 25ns, t<sub>OFF</sub> = 20ns

#### **Ordering Information**

PART	TEMP RANGE	PIN-PACKAGE
MAX4734EUB+	-40°C to +85°C	10 μMAX
MAX4734EUB+T	-40°C to +85°C	10 μMAX
MAX4734ETC+	-40°C to +85°C	12 TQFN (3mm x 3mm)
MAX4734ETC+T	-40°C to +85°C	12 TQFN (3mm x 3mm)

T = Tape and reel.

## Pin Configurations/Functional Diagrams/Truth Table





<sup>+</sup>Denotes a lead (Pb)-free/RoHS-compliant package.

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## **Absolute Maximum Ratings**

(Voltages Referenced to GND)		Continuous Power Dissipation $(T_A = +70^{\circ}C)$	
V+, A_, EN	0.3V to +4V	10-Pin μMAX (derate 5.6mW/°C above +70	0°C)444mW
COM, NO_ (Note 1)0.:	3V to (V+ + 0.3V)	12-Pin Thin QFN (derate 14.7mW/°C above	+70°C) 1176mW
Continuous Current COM, NO	±150mA	Operating Temperature Range	40°C to +85°C
Continuous Current (all other pins)	±20mA	Maximum Junction Temperature	+150°C
Peak Current COM, NO_		Storage Temperature Range	65°C to +150°C
(pulsed at 1ms 10% duty cycle)	±300mA	Lead Temperature (soldering, 10s)	+300°C

Note 1: Signals on COM or NO\_exceeding V+ or GND are clamped by internal diodes. Limit forward current to maximum current rating.

Stresses beyond those listed under "Absolute Maximum Ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated in the operational sections of the specifications is not implied. Exposure to absolute maximum rating conditions for extended periods may affect device reliability.

### **Electrical Characteristics—Single 3V Supply**

 $(V+ = 2.7V \text{ to } 3.6V, V_{IH} = 1.4V, V_{IL} = 0.5V, T_A = T_{MIN} \text{ to } T_{MAX}, \text{ unless otherwise specified. Typical values are at V+ = 3.0V, } T_A = +25^{\circ}C.)$  (Notes 2, 3)

PARAMETER	SYMBOL	CONDITIONS	TA	MIN	TYP	MAX	UNITS	
ANALOG SWITCH	'	,						
Analog Signal Range	V <sub>COM</sub> , V <sub>NO</sub> _			0		V+	V	
On-Resistance (Note 4)		V+ = 2.7V,	+25°C		0.6	0.8	- Ω	
OII-Resistance (Note 4)	R <sub>ON</sub>	I <sub>COM</sub> = 100mA, V <sub>NO</sub> _ = 1.5V	T <sub>MIN</sub> to T <sub>MAX</sub>			1		
On-Resistance Match Between Channels	AD	V+ = 2.7V,	+25°C		0.1	0.2		
(Notes 4, 5)	ΔR <sub>ON</sub>	I <sub>COM</sub> = 100mA, V <sub>NO</sub> _ = 1.5V	T <sub>MIN</sub> to T <sub>MAX</sub>			0.3	Ω	
On-Resistance Flatness (Note 6)	R <sub>FLAT(ON)</sub>	V+ = 2.7V, I <sub>COM</sub> _ = 100mA, V <sub>NO</sub> _ = 1V, 1.5V, 2V	+25°C		0.05	0.1	- Ω	
			T <sub>MIN</sub> to T <sub>MAX</sub>			0.2		
NO Off-Leakage Current		V+ = 3.6V,	+25°C	-1	±0.002	+1	nA	
(Note 7)	I <sub>NO_(OFF)</sub>	V <sub>COM</sub> = 0.3V, 3.3V, V <sub>NO</sub> = 3.3V, 0.3V	T <sub>MIN</sub> to T <sub>MAX</sub>	-5		+5		
COM Off-Leakage Current (Note 7)		V+ = 3.6V,	+25°C	-1	±0.002	+1		
	ICOM(OFF)	V <sub>COM</sub> = 0.3V, 3.3V, V <sub>NO</sub> = 3.3V, 0.3V	T <sub>MIN</sub> to T <sub>MAX</sub> -5	-5		+5	- nA	
COM On-Leakage Current		V+ = 3.6V, V <sub>COM</sub> = 3.3V,	+25°C	-2	±0.002	+2		
(Note 7)	ICOM(ON)	0.3V, V <sub>NO</sub> _ = 3.3V, 0.3V, or floating	T <sub>MIN</sub> to T <sub>MAX</sub>	-10		+10 nA		

## **Electrical Characteristics (continued)**

(V+ = 2.7V to 3.6V,  $V_{IH}$  = 1.4V,  $V_{IL}$  = 0.5V,  $T_A$  =  $T_{MIN}$  to  $T_{MAX}$ , unless otherwise specified. Typical values are at V+ = 3.0V,  $T_A$  = +25°C.) (Notes 2, 3)

PARAMETER	SYMBOL	CONDITIONS	TA	MIN	TYP	MAX	UNITS
SWITCH DYNAMIC CHARACT	ERISTICS						
Turn-On Time	ton	$V_{NO}$ = 1.5V, R <sub>I</sub> = 50 $\Omega$ , C <sub>I</sub> = 35pF,	+25°C		20	25	ns
Tum on Time	JON	Figure 1	T <sub>MIN</sub> to T <sub>MAX</sub>			30	110
Turn-Off Time	t <sub>OFF</sub>	$V_{NO}$ = 1.5V, R <sub>I</sub> = 50 $\Omega$ , C <sub>I</sub> = 35pF,	+25°C		15	20	20 ns
	OFF	Figure 1	T <sub>MIN</sub> to T <sub>MAX</sub>			25	
Break-Before-Make (Note 8)	t <sub>BBM</sub>	$V_{NO}$ = 1.5V, R <sub>L</sub> = 50 $\Omega$ , C <sub>L</sub> = 35pF,	+25°C		5		ns
	-BBIVI	Figure 2	T <sub>MIN</sub> to T <sub>MAX</sub>	1			
Charge Injection	Q	$V_{GEN} = 0$ , $R_{GEN} = 0$ , $C_L = 1.0$ nF, Figure 3	+25°C		60		pC
NO_ Off-Capacitance	C <sub>OFF</sub>	f = 1MHz, Figure 4	+25°C		33		pF
COM Off-Capacitance	C <sub>COM(OFF)</sub>	f = 1MHz, Figure 4	+25°C		117		pF
COM On-Capacitance	C <sub>COM(ON)</sub>	f = 1MHz, Figure 4	+25°C		171		pF
-3dB On-Channel Bandwidth	BW	Signal = 0, $R_{IN} = R_{OUT} = 50\Omega$ , $C_L = 5pF$ , Figure 5			90		MHz
Off-Isolation (Note 9)	V <sub>ISO</sub>	$f = 1MHz$ , $V_{COM} = 1$ $V_{P-P}$ , $R_L = 50\Omega$ , $C_L = 5pF$ , Figure 5	+25°C		-56		dB
Crosstalk (Note 10)	V <sub>CT</sub>	$f = 1MHz$ , $V_{COM} = 1$ $V_{P-P}$ , $R_L = 50\Omega$ , $C_L = 5pF$ , Figure 5	+25°C		-56		dB
Total Harmonic Distortion	THD	f = 20Hz to 20kHz, V <sub>COM</sub> = 2V <sub>P-P</sub> , R <sub>L</sub> = 32Ω	+25°C		0.018		%
LOGIC INPUT (A_, EN)							
Input Logic High	V <sub>IH</sub>			1.4			V
Input Logic Low	V <sub>IL</sub>					0.5	V
Input Leakage Current	IIN	V <sub>EN</sub> = 0 or 3.6V, V <sub>A</sub> _ = 0 or 3.6V		-1	0.005	+1	μA
POWER SUPPLY							
Power-Supply Range	V+			1.6		3.6	V
Positive Supply Current	I+	V+ = 3.6V, V <sub>EN, A</sub> _ = 0 or V+, all channels on or off			0.004	1	μΑ

### **Electrical Characteristics—Single 1.8V Supply**

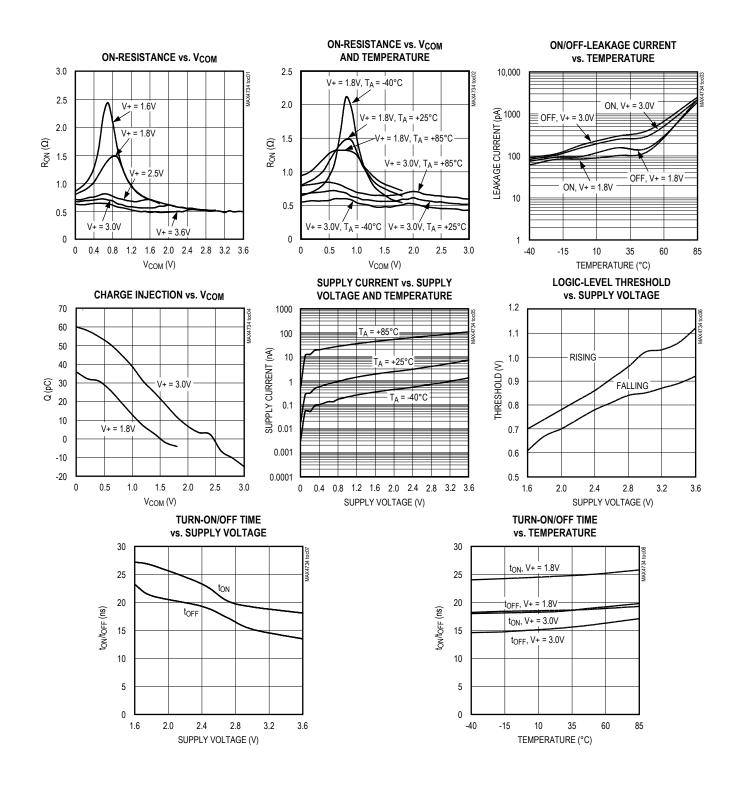
 $(V + = 1.8V, V_{IH} = 1.0V, V_{IL} = 0.4V, T_A = T_{MIN} \text{ to } T_{MAX}, \text{ unless otherwise specified. Typical values are at } T_A = +25^{\circ}C.) (Notes 2, 3)$ 

PARAMETER	SYMBOL	CONDITIONS	TA	MIN	TYP	MAX	UNITS
ANALOG SWITCH							
Analog Signal Range	V <sub>COM</sub> , V <sub>NO</sub> _			0		V+	V
On-Resistance	Pou	I <sub>COM</sub> _ = 10mA,	+25°C		1.5	2	Ω
On-Resistance	R <sub>ON</sub>	V <sub>NO</sub> _= 1V	T <sub>MIN</sub> to T <sub>MAX</sub>			3	22
SWITCH DYNAMIC CHARACT	ERISTICS						·
Turn-On Time	t <sub>ON</sub>	$V_{NO}$ = 1V, $R_1 = 50\Omega \square C_1 = 35pF$ ,	+25°C		25	30	ns
	-011	Figure 1	T <sub>MIN</sub> to T <sub>MAX</sub>			35	
Turn Off Time		V <sub>NO</sub> _ = 1V,	+25°C		18	25	ns
Turn-Off Time	toff	$R_L = 50\Omega \square C_L = 35pF,$ Figure 1	T <sub>MIN</sub> to T <sub>MAX</sub>			28	
		V <sub>NO</sub> _= 1V,	+25°C		7		
Break-Before-Make (Note 8)	t <sub>BBM</sub>	$R_L = 50\Omega \square C_L = 35pF,$ Figure 2	T <sub>MIN</sub> to T <sub>MAX</sub>	1			ns
Charge Injection	Q	$V_{GEN} = 0$ , $R_{GEN} = 0$ , $C_L = 1$ nF, Figure 3	+25°C		35		рС
Off-Isolation (Note 9)	V <sub>ISO</sub>	$f = 1 MHz, V_{NO} = 1 V_{P-P},$ $R_L = 50 \Omega,$ $C_L = 5 pF, Figure 5$	+25°C		-56		dB
Crosstalk (Note 10)	V <sub>CT</sub>	$f = 1 \text{MHz}, V_{COM} = 1 V_{P-P},$ $R_L = 50 \Omega,$ $C_L = 5 \text{pF}, \text{Figure 5}$	+25°C		-56		dB
LOGIC INPUT (A_, EN)							
Input Logic High	V <sub>IH</sub>			1			V
Input Logic Low	V <sub>IL</sub>					0.4	V
Input Leakage Current	I <sub>IN</sub>	V <sub>EN</sub> = 0 or 3.6V, V <sub>A</sub> _ = 0 or 3.6V				1	μA

- **Note 2:** The algebraic convention, where the most negative value is a minimum and the most positive value is a maximum, is used in this data sheet.
- **Note 3:** -40°C specifications are guaranteed by design.
- **Note 4:**  $R_{ON}$  and  $\Delta R_{ON}$  matching specifications for thin QFN packaged parts are guaranteed by design.
- **Note 5:**  $\Delta R_{ON} = R_{ON(MAX)} R_{ON(MIN)}$
- **Note 6:** Flatness is defined as the difference between the maximum and the minimum value of on-resistance as measured over the specified analog signal ranges.
- Note 7: Leakage parameters are 100% tested at hot temperature and guaranteed by correlation at room temperature.
- Note 8: Guaranteed by design.
- **Note 9:** Off-Isolation =  $20\log_{10}(V_{COM}/V_{NO})$ ,  $V_{COM}$  = output,  $V_{NO}$  = input to off switch.
- Note 10: Between two switches.

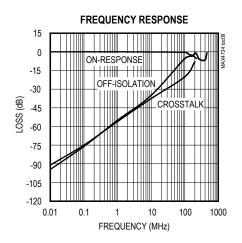
## **Typical Operating Characteristics**

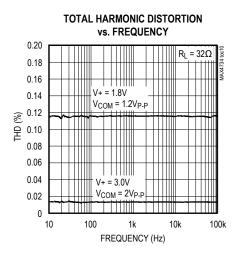
(TA = +25°C, unless otherwise noted.)



## **Typical Operating Characteristics (continued)**

(T<sub>A</sub> = +25°C, unless otherwise noted.)





## **Pin Description**

Р	IN	NAME	FUNCTION	
μМΑХ	QFN			
1	12	A0	Address 0 Input	
2	1	NO1	Analog Switch 1—Normally Open Terminal	
3	2	GND	Ground	
4	3	NO3	Analog Switch 3—Normally Open Terminal	
5	4	EN	Enable Logic Input	
6	6	V+	Positive-Supply Voltage Input	
7	7	NO4	Analog Switch 4—Normally Open Terminal	
8	8	COM	Analog Switch Common Terminal	
9	9	NO2	Analog Switch 2—Normally Open Terminal	
10	10	A1	Address 1 Input	
_	5, 11	N.C.	No Connection. Not internally connected.	
_	_	EP	Exposed Pad. Connect to Ground.	

#### **Detailed Description**

The MAX4734 is a low  $0.8\Omega$  (max) (at V+ = 2.7V) on-resistance, low-voltage, 4-channel CMOS analog multiplexer that operates from a 1.6V to 3.6V single supply. CMOS switch construction allows switching analog signals that range from GND to V+.

When powered from a 2.7V supply, the 0.8 $\Omega$  (max) R<sub>ON</sub> allows high continuous currents to be switched in a variety of applications.

#### **Applications Information**

Proper power-supply sequencing is recommended for all CMOS devices. Do not exceed the absolute maximum ratings, because stresses beyond the listed ratings can cause permanent damage to the devices. Always sequence V+ on first, followed by NO\_ or COM.

Although it is not required, power-supply bypassing improves noise margin and prevents switching noise propagation from the V+ supply to other components. A  $0.1\mu F$  capacitor, connected from V+ to GND, is adequate for most applications.

#### **Logic Inputs**

The MAX4734 logic inputs can be driven up to 3.6V regardless of the supply voltage. For example, with a 1.8V supply, A\_ and EN may be driven low to GND and high to 3.6V. Driving A\_ and EN rail-to-rail minimizes power consumption.

#### **Analog Signal Levels**

Analog signals that range over the entire supply voltage (V+ to GND) can be passed with very little change in onresistance (see the *Typical Operating Characteristics*). The switches are bidirectional, so the NO\_ and COM\_ pins can be used as either inputs or outputs.

#### Layout

High-speed switches require proper layout and design procedures for optimum performance. Reduce stray inductance and capacitance by keeping traces short and wide. Ensure that bypass capacitors are as close to the device as possible. Use large ground planes where possible.

#### **Test Circuits/Timing Diagrams**

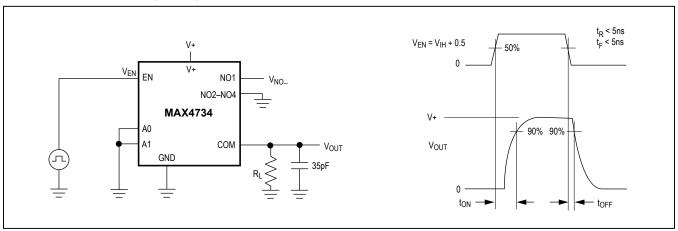


Figure 1. Switching Time

## **Test Circuits/Timing Diagrams (continued)**

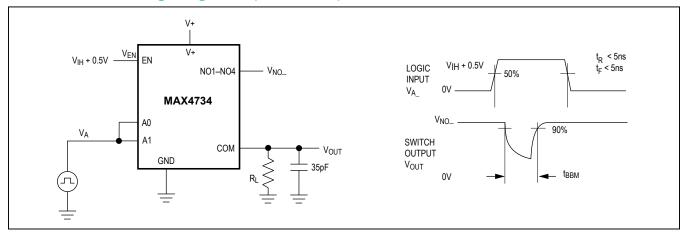


Figure 2. Break-Before-Make Interval

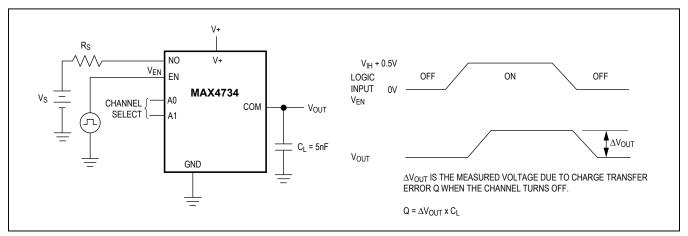


Figure 3. Charge Injection

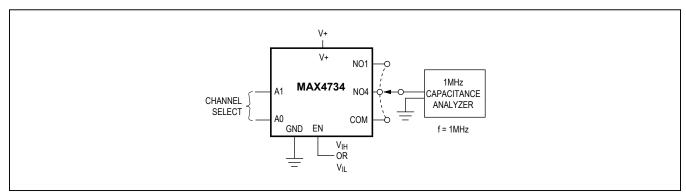


Figure 4. Channel Off/On-Capacitance

## **Test Circuits/Timing Diagrams (continued)**

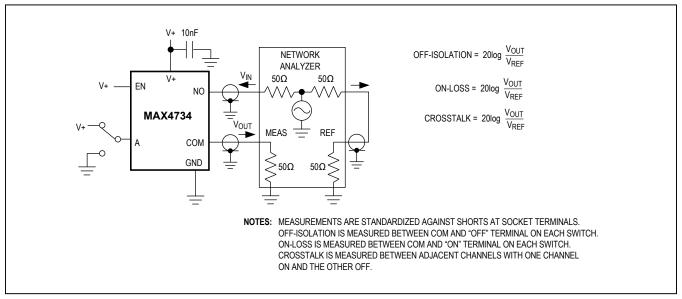


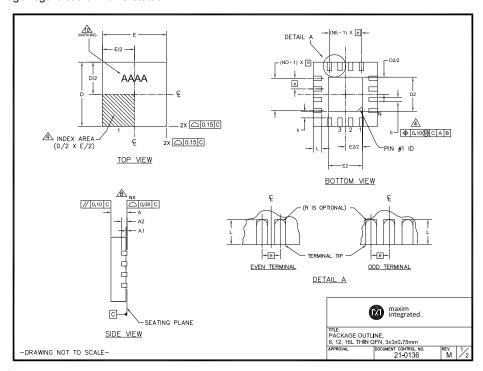
Figure 5. Off-Isolation/On-Channel/Crosstalk Bandwidth

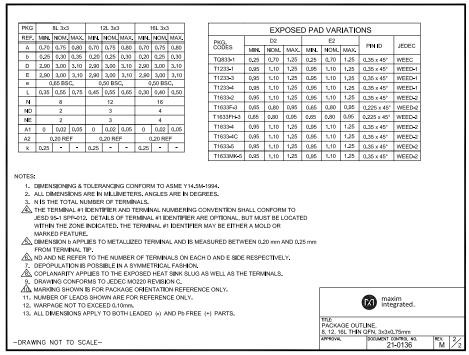
## **Chip Information**

TRANSISTOR COUNT: 379 PROCESS: CMOS

#### **Package Information**

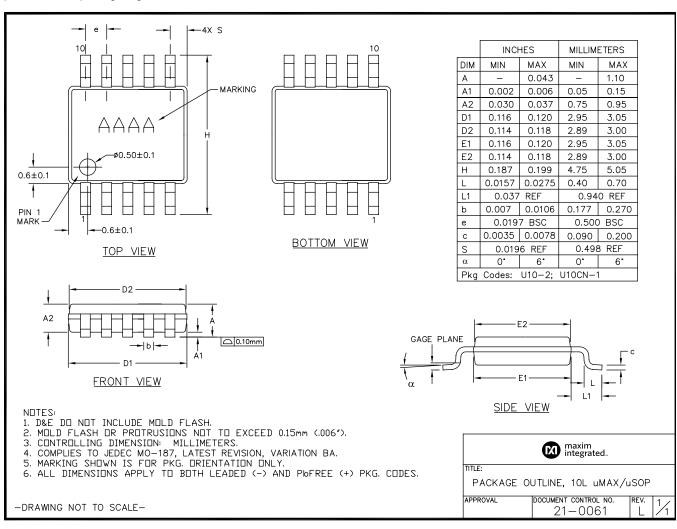
For the latest package outline information and land patterns (footprints), go to <a href="www.maximintegrated.com/packages">www.maximintegrated.com/packages</a>. Note that a "+", "#", or "-" in the package code indicates RoHS status only. Package drawings may show a different suffix character, but the drawing pertains to the package regardless of RoHS status.





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#### MAX4734

## 0.8Ω, Low-Voltage, 4-Channel **Analog Multiplexer**

## **Revision History**

REVISION	REVISION	DESCRIPTION	PAGES
NUMBER	DATE		CHANGED
2	10/16	Updated Ordering Information table and clarified package options	1

For pricing, delivery, and ordering information, please contact Maxim Direct at 1-888-629-4642, or visit Maxim Integrated's website at www.maximintegrated.com.

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